# **Quad 2-Input NOR Gate**

- Outputs Source/Sink 24 mA
- 'ACT02 Has TTL Compatible Inputs

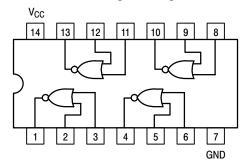


Figure 1. Pinout: 14-Lead Packages Conductors (Top View)

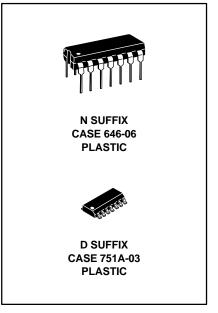
### **MAXIMUM RATINGS\***

Symbol	Parameter	Value	Unit
V <sub>CC</sub>	DC Supply Voltage (Referenced to GND)	-0.5 to +7.0	V
V <sub>in</sub>	DC Input Voltage (Referenced to GND)	–0.5 to V <sub>CC</sub> +0.5	V
V <sub>out</sub>	DC Output Voltage (Referenced to GND)	-0.5 to V <sub>CC</sub> +0.5	V
I <sub>in</sub>	DC Input Current, per Pin	±20	mA
l <sub>out</sub>	DC Output Sink/Source Current, per Pin	±50	mA
I <sub>CC</sub>	DC V <sub>CC</sub> or GND Current per Output Pin	±50	mA
T <sub>stg</sub>	Storage Temperature	-65 to +150	°C

<sup>\*</sup> Maximum Ratings are those values beyond which damage to the device may occur. Functional operation should be restricted to the Recommended Operating Conditions.

# MC74AC02 MC74ACT02

QUAD 2-INPUT NOR GATE



# **RECOMMENDED OPERATING CONDITIONS**

Symbol	Parameter		Min	Тур	Max	Unit	
	Out to Malla and	'AC	2.0	5.0	6.0	.,	
V <sub>CC</sub>	Supply Voltage	'ACT	4.5	5.0	5.5	V	
V <sub>in</sub> , V <sub>out</sub>	DC Input Voltage, Output Voltage (Ref. to GND)	•	0		V <sub>CC</sub>	V	
		V <sub>CC</sub> @ 3.0 V		150			
t <sub>r</sub> , t <sub>f</sub>	Input Rise and Fall Time (Note 1)  'AC Devices except Schmitt Inputs	V <sub>CC</sub> @ 4.5 V		40		ns/V	
	AC BONISS SKOOPL COMMIN INPULS	V <sub>CC</sub> @ 5.5 V		25			
	Input Rise and Fall Time (Note 2)	V <sub>CC</sub> @ 4.5 V		10		01	
t <sub>r</sub> , t <sub>f</sub>	'ACT Devices except Schmitt Inputs	V <sub>CC</sub> @ 5.5 V		8.0		ns/V	
TJ	Junction Temperature (PDIP)				140	°C	
T <sub>A</sub>	Operating Ambient Temperature Range		-40	25	85	°C	
I <sub>OH</sub>	Output Current — High				-24	mA	
I <sub>OL</sub>	Output Current — Low				24	mA	

<sup>1.</sup>  $V_{in}$  from 30% to 70%  $V_{CC}$ ; see individual Data Sheets for devices that differ from the typical input rise and fall times.

<sup>2.</sup> V<sub>in</sub> from 0.8 V to 2.0 V; see individual Data Sheets for devices that differ from the typical input rise and fall times.

### **DC CHARACTERISTICS**

	Parameter		74AC T <sub>A</sub> = +25°C		74AC		Conditions	
Symbol		V <sub>CC</sub> (V)			T <sub>A</sub> = -40°C to +85°C	Unit		
			Тур	Guar	anteed Limits			
V <sub>IH</sub>	Minimum High Level Input Voltage	3.0 4.5 5.5	1.5 2.25 2.75	2.1 3.15 3.85	2.1 3.15 3.85	V	V <sub>OUT</sub> = 0.1 V or V <sub>CC</sub> – 0.1 V	
V <sub>IL</sub>	Maximum Low Level Input Voltage	3.0 4.5 5.5	1.5 2.25 2.75	0.9 1.35 1.65	0.9 1.35 1.65	V	V <sub>OUT</sub> = 0.1 V or V <sub>CC</sub> – 0.1 V	
V <sub>OH</sub>	Minimum High Level Output Voltage	3.0 4.5 5.5	2.99 4.49 5.49	2.9 4.4 5.4	2.9 4.4 5.4	V	Ι <sub>ΟυΤ</sub> = –50 μΑ	
		3.0 4.5 5.5		2.56 3.86 4.86	2.46 3.76 4.76	V	*V <sub>IN</sub> = V <sub>IL</sub> or V <sub>IH</sub> -12 mA I <sub>OH</sub> -24 mA -24 mA	
V <sub>OL</sub>	Maximum Low Level Output Voltage	3.0 4.5 5.5	0.002 0.001 0.001	0.1 0.1 0.1	0.1 0.1 0.1	V	Ι <sub>ΟυΤ</sub> = 50 μΑ	
		3.0 4.5 5.5		0.36 0.36 0.36	0.44 0.44 0.44	V	$^{*}V_{IN} = V_{IL} \text{ or } V_{IH}$ $12 \text{ mA}$ $I_{OL}$ $24 \text{ mA}$ $24 \text{ mA}$	
I <sub>IN</sub>	Maximum Input Leakage Current	5.5		±0.1	±1.0	μΑ	V <sub>I</sub> = V <sub>CC</sub> , GND	
I <sub>OLD</sub>	†Minimum Dynamic	5.5			75	mA	V <sub>OLD</sub> = 1.65 V Max	
I <sub>OHD</sub>	Output Current	5.5			<b>-75</b>	mA	V <sub>OHD</sub> = 3.85 V Min	
I <sub>CC</sub>	Maximum Quiescent Supply Current	5.5		4.0	40	μА	V <sub>IN</sub> = V <sub>CC</sub> or GND	

<sup>\*</sup> All outputs loaded; thresholds on input associated with output under test.

Note:  $I_{IN}$  and  $I_{CC}$  @ 3.0 V are guaranteed to be less than or equal to the respective limit @ 5.5 V  $V_{CC}$ .

# AC CHARACTERISTICS (For Figures and Waveforms — See Section 3 of the ON Semiconductor FACT Data Book, DL138/D)

			74AC			74AC			
Symbol	Parameter	V <sub>CC</sub> * (V)		<sub>A</sub> = +25° S <sub>L</sub> = 50 p		T <sub>A</sub> = - to +8 C <sub>L</sub> = 9		Unit	Fig. No.
			Min	Тур	Max	Min	Max		
t <sub>PLH</sub>	Propagation Delay	3.3 5.0	1.5 1.5	5.0 4.0	7.5 6.0	1.0 1.0	8.0 6.5	ns	3-5
t <sub>PHL</sub>	Propagation Delay	3.3 5.0	1.5 1.5	5.0 4.5	7.5 6.5	1.0 1.0	8.0 7.0	ns	3-5

 $<sup>^*</sup>$  Voltage Range 3.3 V is 3.3 V  $\pm 0.3$  V. Voltage Range 5.0 V is 5.0 V  $\pm 0.5$  V.

<sup>†</sup>Maximum test duration 2.0 ms, one output loaded at a time.

# **DC CHARACTERISTICS**

	Parameter		74ACT  T <sub>A</sub> = +25°C		74ACT	Unit	
Symbol		V <sub>CC</sub> (V)			T <sub>A</sub> = -40°C to +85°C		Conditions
			Тур	Guar	anteed Limits		
V <sub>IH</sub>	Minimum High Level Input Voltage	4.5 5.5	1.5 1.5	2.0 2.0	2.0 2.0	V	V <sub>OUT</sub> = 0.1 V or V <sub>CC</sub> – 0.1 V
V <sub>IL</sub>	Maximum Low Level Input Voltage	4.5 5.5	1.5 1.5	0.8 0.8	0.8 0.8	V	V <sub>OUT</sub> = 0.1 V or V <sub>CC</sub> – 0.1 V
V <sub>OH</sub>	Minimum High Level Output Voltage	4.5 5.5	4.49 5.49	4.4 5.4	4.4 5.4	V	I <sub>OUT</sub> = -50 μA
		4.5 5.5		3.86 4.86	3.76 4.76	V	*V <sub>IN</sub> = V <sub>IL</sub> or V <sub>IH</sub> -24 mA I <sub>OH</sub> -24 mA
V <sub>OL</sub>	Maximum Low Level Output Voltage	4.5 5.5	0.001 0.001	0.1 0.1	0.1 0.1	V	I <sub>OUT</sub> = 50 μA
		4.5 5.5		0.36 0.36	0.44 0.44	V	*V <sub>IN</sub> = V <sub>IL</sub> or V <sub>IH</sub> 24 mA I <sub>OL</sub> 24 mA
I <sub>IN</sub>	Maximum Input Leakage Current	5.5		±0.1	±1.0	μΑ	$V_1 = V_{CC}$ , GND
$\Delta I_{CCT}$	Additional Max. I <sub>CC</sub> /Input	5.5	0.6		1.5	mA	$V_{I} = V_{CC} - 2.1 \text{ V}$
I <sub>OLD</sub>	†Minimum Dynamic	5.5			75	mA	V <sub>OLD</sub> = 1.65 V Max
I <sub>OHD</sub>	Output Current	5.5			<b>-75</b>	mA	V <sub>OHD</sub> = 3.85 V Min
I <sub>CC</sub>	Maximum Quiescent Supply Current	5.5		4.0	40	μΑ	V <sub>IN</sub> = V <sub>CC</sub> or GND

<sup>\*</sup> All outputs loaded; thresholds on input associated with output under test.

### AC CHARACTERISTICS (For Figures and Waveforms — See Section 3 of the ON Semiconductor FACT Data Book, DL138/D)

			74ACT			74ACT			
Symbol	Parameter	V <sub>CC</sub> * (V)		<sub>A</sub> = +25° <sub>L</sub> = 50 p		T <sub>A</sub> = - to +8 C <sub>L</sub> = 9		Unit	Fig. No.
			Min	Тур	Max	Min	Max		
t <sub>PLH</sub>	Propagation Delay	5.0	1.5		8.5	1.0	9.0	ns	3-6
t <sub>PHL</sub>	Propagation Delay	5.0	1.5		9.5	1.0	10	ns	3-6

 $<sup>^{\</sup>star}$  Voltage Range 5.0 V is 5.0 V  $\pm 0.5$  V.

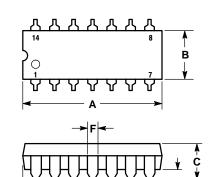
# **CAPACITANCE**

Symbol	Parameter	Value Typ	Unit	Test Conditions
C <sub>IN</sub>	Input Capacitance	4.5	pF	V <sub>CC</sub> = 5.0 V
C <sub>PD</sub>	Power Dissipation Capacitance	30	pF	V <sub>CC</sub> = 5.0 V

<sup>†</sup>Maximum test duration 2.0 ms, one output loaded at a time.

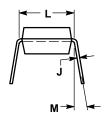
# **OUTLINE DIMENSIONS**

**N SUFFIX** PLASTIC DIP PACKAGE CASE 646–06 ISSUE L



> G <

SEATING PLANE



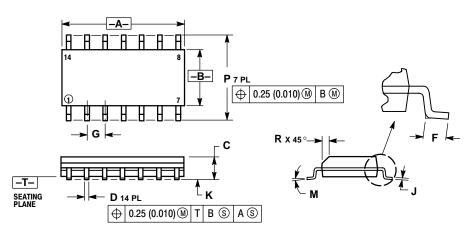
- NOTES:
  1. LEADS WITHIN 0.13 (0.005) RADIUS OF TRUE POSITION AT SEATING PLANE AT MAXIMUM MATERIAL CONDITION.
  2. DIMENSION L TO CENTER OF LEADS WHEN FORMED PARALLEL.
  3. DIMENSION B DOES NOT INCLUDE MOLD ELACH.
- FLASH.
  4. ROUNDED CORNERS OPTIONAL.

	INC	HES	MILLIN	IETERS	
DIM	MIN	MAX	MIN	MAX	
Α	0.715	0.770	18.16	19.56	
В	0.240	0.260	6.10	6.60	
С	0.145	0.185	3.69	4.69	
D	0.015	0.021	0.38	0.53	
F	0.040	0.070	1.02	1.78	
G	0.100	BSC	2.54 BSC		
Н	0.052	0.095	1.32	2.41	
J	0.008	0.015	0.20	0.38	
K	0.115	0.135	2.92	3.43	
L	0.300	0.300 BSC		BSC	
М	0°	10°	0°	10°	
N	0.015	0.039	0.39	1.01	

# **OUTLINE DIMENSIONS**

### **D SUFFIX**

PLASTIC SOIC PACKAGE CASE 751A-03 ISSUE F



### NOTES:

- NOTES:

  1. DIMEN SIONING AND TOLERANCING PER ANSI 714.5M, 1982.

  2. CONTROLLING DIMENSION: MILLIMETER.

  3. DIMENSIONS A AND B DO NOT INCLUDE MOLD PROTRUSION.

  4. MAXIMUM MOLD PROTRUSION 0.15 (0.006) PER SIDE.

  5. DIMENSION D DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE DAMBAR PROTRUSION SHALL BE 0.127 (0.005) TOTAL IN EXCESS OF THE D DIMENSION AT MAXIMUM MATERIAL CONDITION.

	MILLIN	METERS	INC	HES	
DIM	MIN	MAX	MIN	MAX	
Α	8.55	8.75	0.337	0.344	
В	3.80	4.00	0.150	0.157	
С	1.35	1.75	0.054	0.068	
D	0.35	0.49	0.014	0.019	
F	0.40	1.25	0.016	0.049	
G	1.27	BSC	0.050 BSC		
J	0.19	0.25	0.008	0.009	
K	0.10	0.25	0.004	0.009	
M	0 °	7°	0 °	7°	
Р	5.80	6.20	0.228	0.244	
R	0.25	0.50	0.010	0.019	





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